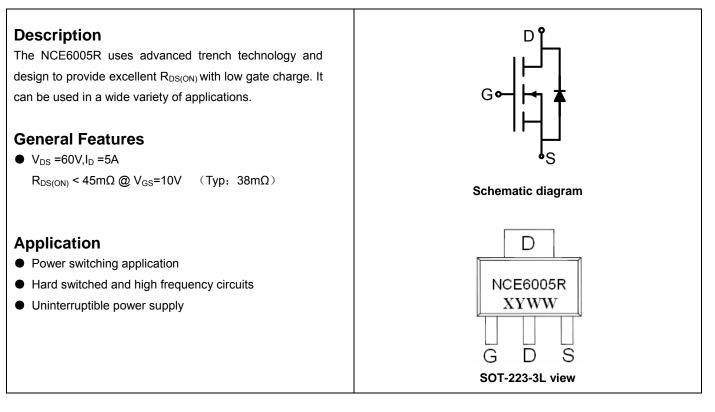




NCE N-Channel Enhancement Mode Power MOSFET



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE6005R	NCE6005R	SOT-223-3L	Ø330mm	12mm	2500 units

Absolute Maximum Ratings (T_A=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	60	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	Ι _D	5	А
Drain Current-Continuous(T _C =100°C)	I _D (100℃)	3.5	A
Pulsed Drain Current	I _{DM}	20	А
Maximum Power Dissipation	P _D	2	W
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient ^(Note 2)	R _{0JA}	62.5	°C /W
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Electrical Characteristics (T_A=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	60	69	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =60V, V_{GS} =0V	-	-	1	μA



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NCE6005R

Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)	<u> </u>					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.2	2	2.5	V
Drain-Source On-State Resistance	R _{DS(ON)}	V_{GS} =10V, I _D =4.5A		38	45	
Forward Transconductance	g fs	V _{DS} =5V,I _D =4.5A	11	-	-	S
Dynamic Characteristics (Note4)	····					
Input Capacitance	Clss	\/ - 25\/\/ - 0\/		450		PF
Output Capacitance	C _{oss}	V _{DS} =25V,V _{GS} =0V, F=1.0MHz		60		PF
Reverse Transfer Capacitance	Crss			25		PF
Switching Characteristics (Note 4)	· · · · ·					
Turn-on Delay Time	t _{d(on)}		-	4.7	-	nS
Turn-on Rise Time	tr	V_{Ds} =30V,I _D =4.5A	-	2.3	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{GEN} =3 Ω	-	15.7	-	nS
Turn-Off Fall Time	t _f		-	1.9	-	nS
Total Gate Charge	Qg	V -20V/L -4 FA	-	8.5	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =30V,I _D =4.5A, V _{GS} =10V	-	1.6	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} -10V	-	2.2	-	nC
Drain-Source Diode Characteristics	····					
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =5A	-	-	1.2	V
Diode Forward Current (Note 2)	I _S		-	-	5	А

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, t \leq 10 sec.

3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production

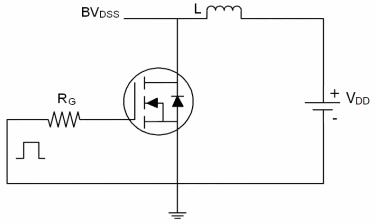


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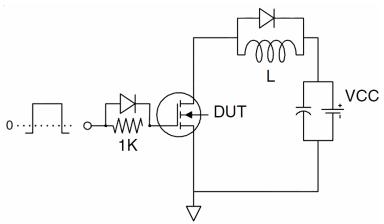




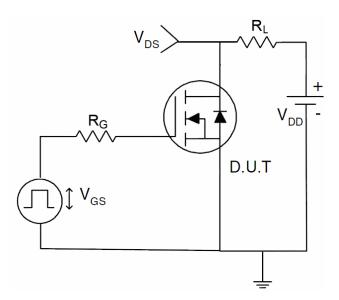
Test Circuit 1) E_{AS} Test Circuit



2) Gate Charge Test Circuit



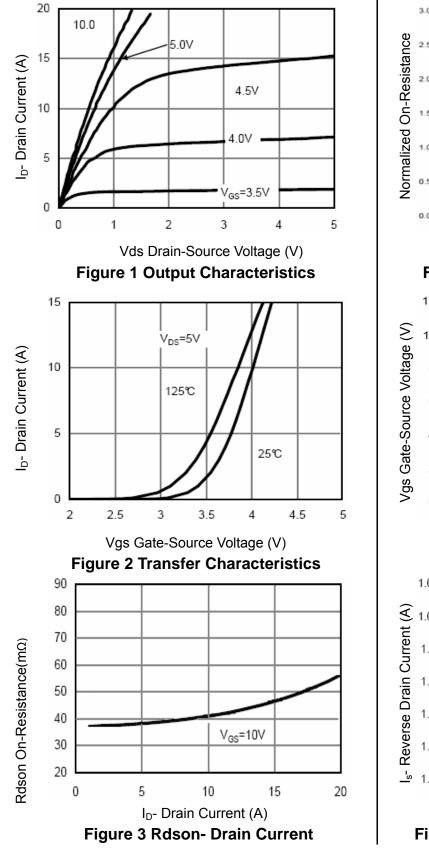
3) Switch Time Test Circuit

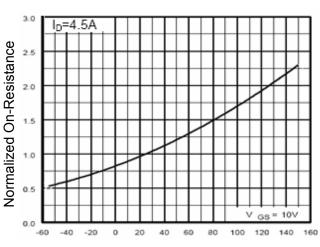






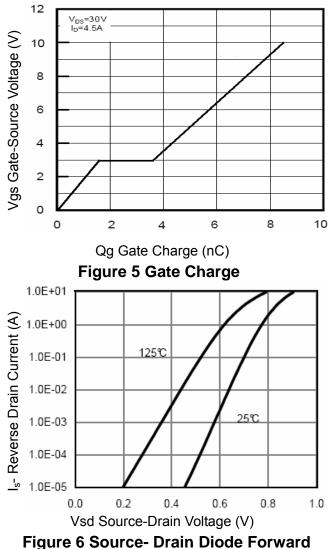
Typical Electrical and Thermal Characteristics (Curves)





 T_J -Junction Temperature($^{\circ}C$)

Figure 4 Rdson-Junction Temperature





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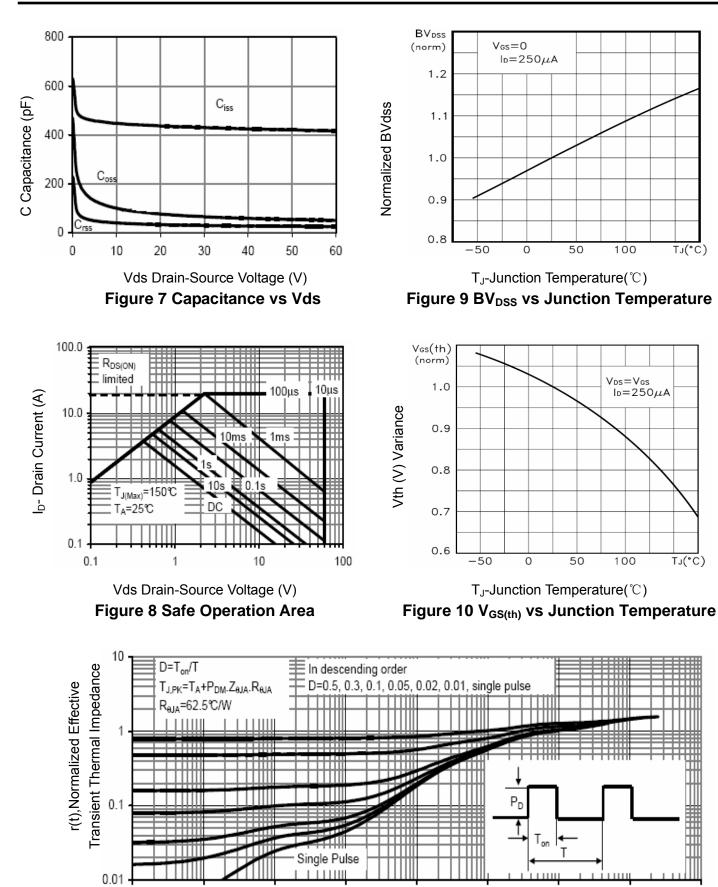


Figure 11 Normalized Maximum Transient Thermal Impedance

0.1

1

10

100

0.0001

0.00001

0.01

0.001

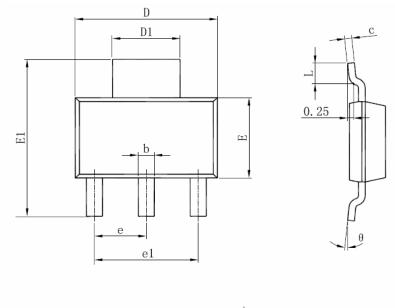
1000







SOT-223-3L Package Information





Querra la	Dimensions Ir	n Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	1.520	1.800	0.060	0.071	
A1	0.000	0.100	0.000	0.004	
A2	1.500	1.700	0.059	0.067	
b	0.660	0.820	0.026	0.032	
с	0.250	0.350	0.010	0.014	
D	6.200	6.400	0.244	0.252	
D1	2.900	3.100	0.114	0.122	
E	3.300	3.700	0.130	0.146	
E1	6.830	7.070	0.269	0.278	
e	2.300(BSC)		0.091(BSC)	
e1	4.500	4.700	0.177	0.185	
L	0.900	1.150	0.035	0.045	
θ	0°	10°	0°	10°	

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ± 0.10 mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.







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